## NSN 5961-01-160-2933

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-160-2933 **Inclosure Material:** Metal **Overall Length:** 1.563 inches **Overall Height:** 0.350 inches **Overall Width:** 1.050 inches **End Application:** 1560-k0-158-032a **Mounting Facility Quantity: Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 8.00 amperes source cutoff current of standard range and 20.00 amperes forward current, average any acceptable **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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